



PJT7601

20V Complementary Enhancement Mode MOSFET – ESD Protected

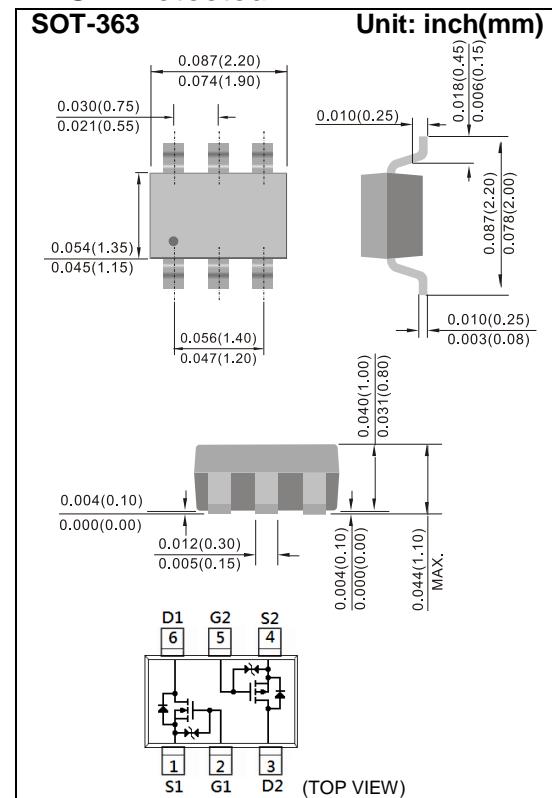
Voltage **20/-20V** **Current** **0.5/-0.5A**

Features

- Low Voltage Drive (1.2V)
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-363 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0002 ounces, 0.006 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS
Drain-Source Voltage	V_{DS}	20	-20	V
Gate-Source Voltage	V_{GS}	± 10	± 10	V
Continuous Drain Current	I_D	0.5	-0.5	A
Pulsed Drain Current ^(Note 4)	I_{DM}	1.0	-1.0	A
Power Dissipation	$T_a=25^\circ\text{C}$	P_D	350	mW
	Derate above 25°C		2.8	$\text{mW}/^\circ\text{C}$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	$-55 \sim 150$		$^\circ\text{C}$
Typical Thermal resistance - Junction to Ambient ^(Note 3)	$R_{\theta JA}$	357		$^\circ\text{C}/\text{W}$



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N-Channel Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D= 250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D= 250\mu A$	0.3	0.65	0.9	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}= 4.5V, I_D= 500mA$	-	280	400	$m\Omega$
		$V_{GS}= 2.5V, I_D= 200mA$	-	350	650	
		$V_{GS}= 1.8V, I_D= 100mA$	-	400	800	
		$V_{GS}= 1.5V, I_D= 50mA$	-	500	1200	
		$V_{GS}= 1.2V, I_D= 20mA$	-	700	3000	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=16V, V_{GS}=0V$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	± 0.5	± 10	μA
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	$V_{DS}=10V, I_D=500mA,$ $V_{GS}=4.5V$ <small>(Note 1,2)</small>	-	1.4	-	nC
Gate-Source Charge	Q_{gs}		-	0.22	-	
Gate-Drain Charge	Q_{gd}		-	0.21	-	
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V,$ $f=1.0MHz$	-	67	-	pF
Output Capacitance	C_{oss}		-	19	-	
Reverse Transfer Capacitance	C_{rss}		-	6	-	
Switching						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=150mA,$ $V_{GS}=4.0V, R_G=10\Omega$ <small>(Note 1,2)</small>	-	2.8	-	ns
Turn-On Rise Time	t_r		-	20	-	
Turn-Off Delay Time	$t_{d(off)}$		-	23	-	
Turn-Off Fall Time	t_f		-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s	---	-	-	500	mA
Diode Forward Voltage	V_{SD}	$I_s= 500mA, V_{GS}=0V$	-	0.87	1.3	V



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PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D= -250\mu A$	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D= -250\mu A$	-0.3	-0.6	-1	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}= -4.5V, I_D= -500mA$	-	850	1200	$m\Omega$
		$V_{GS}= -2.5V, I_D= -200mA$	-	990	1500	
		$V_{GS}= -1.8V, I_D= -100mA$	-	1160	2200	
		$V_{GS}= -1.5V, I_D= -50mA$	-	1330	3600	
		$V_{GS}= -1.2V, I_D= -10mA$	-	1500	6000	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-16V, V_{GS}=0V$	-	-	-1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	± 2	± 10	μA
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	$V_{DS}=-10V, I_D=-500mA,$ $V_{GS}=-4.5V$ ^(Note 1,2)	-	1.4	-	nC
Gate-Source Charge	Q_{gs}		-	0.19	-	
Gate-Drain Charge	Q_{gd}		-	0.2	-	
Input Capacitance	C_{iss}	$V_{DS}=-10V, V_{GS}=0V,$ $f=1.0MHz$	-	38	-	pF
Output Capacitance	C_{oss}		-	15	-	
Reverse Transfer Capacitance	C_{rss}		-	9	-	
Switching						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-10V, I_D=-500mA,$ $V_{GS}=-4.5V, R_G=6\Omega$ ^(Note 1,2)	-	7.2	-	ns
Turn-On Rise Time	t_r		-	21	-	
Turn-Off Delay Time	$t_{d(off)}$		-	85	-	
Turn-Off Fall Time	t_f		-	116	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s	---	-	-	-500	mA
Diode Forward Voltage	V_{SD}	$I_s=-500mA, V_{GS}=0V$	-	-0.93	-1.3	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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N-Channel TYPICAL CHARACTERISTIC CURVES

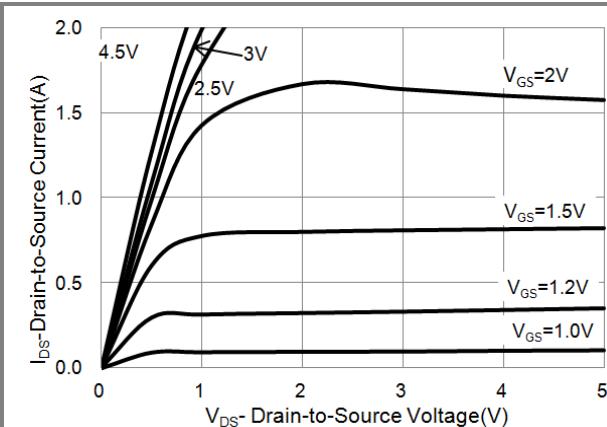


Fig.1 On-Region Characteristics

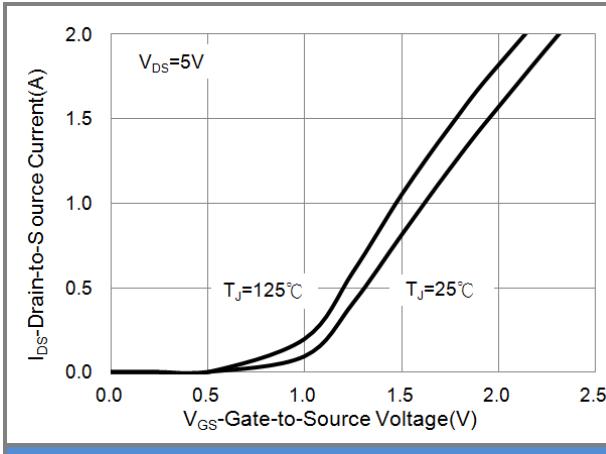


Fig.2 Transfer Characteristics

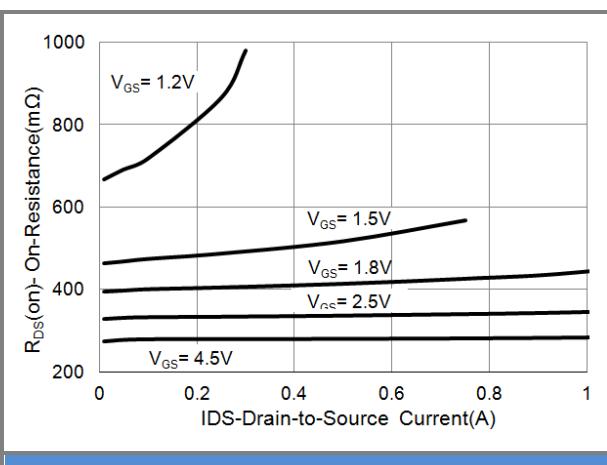


Fig.3 On-Resistance vs. Drain Current

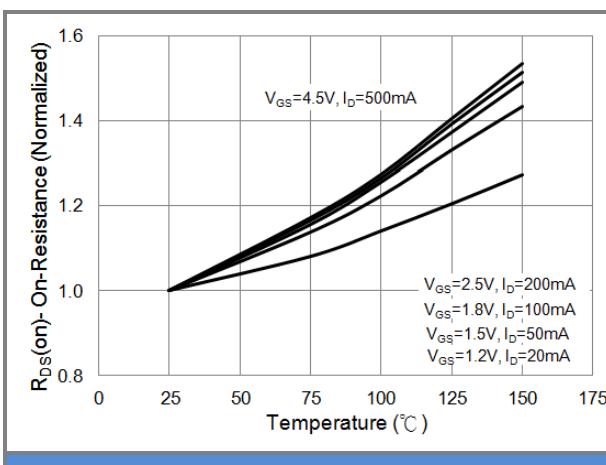


Fig.4 On-Resistance vs. Junction temperature

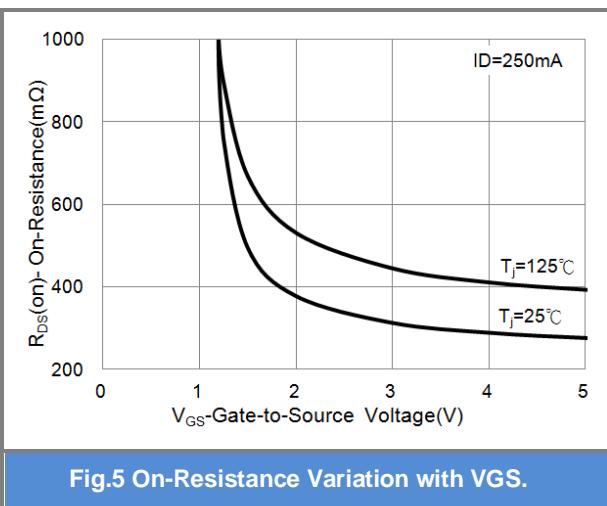


Fig.5 On-Resistance Variation with VGS.

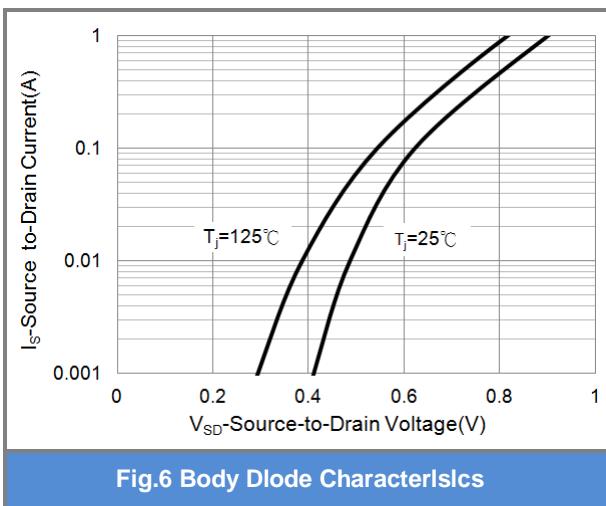
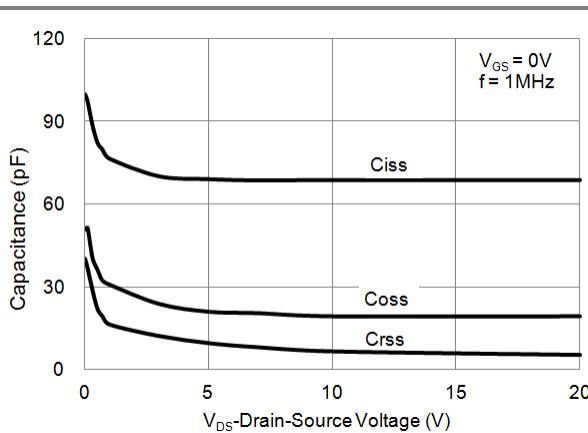
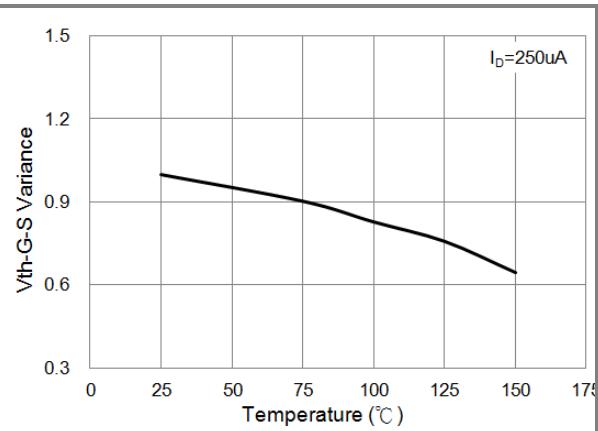
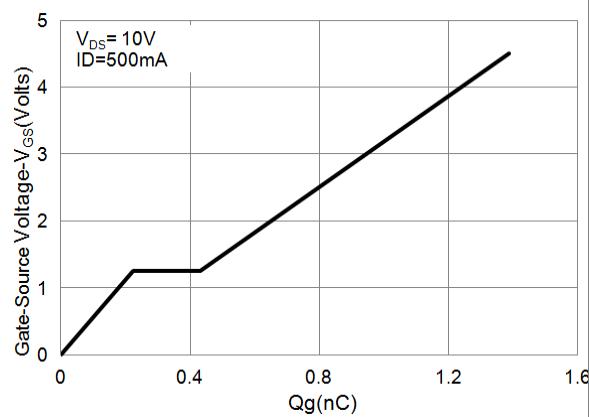


Fig.6 Body Diode Characteristics



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N-Channel TYPICAL CHARACTERISTIC CURVES





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P-Channel TYPICAL CHARACTERISTIC CURVES

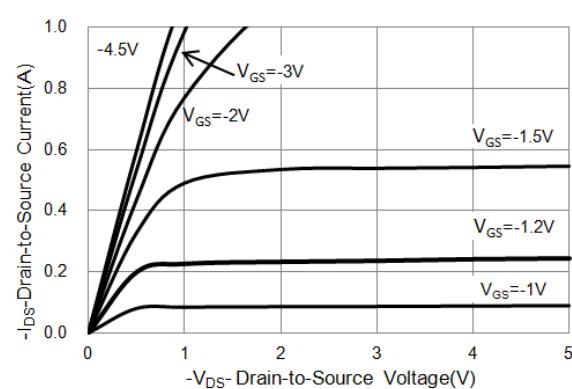


Fig.1 On-Region Characteristics

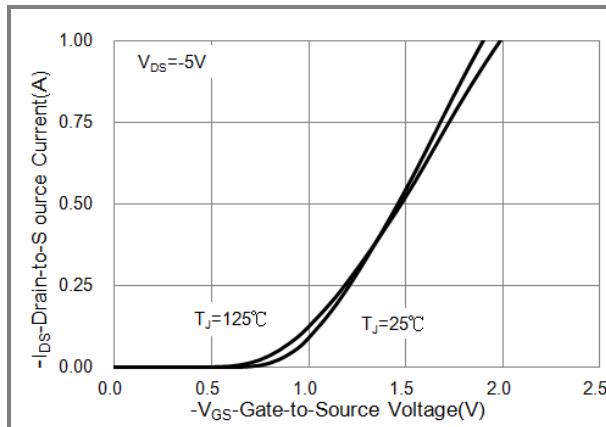


Fig.2 Transfer Characteristics

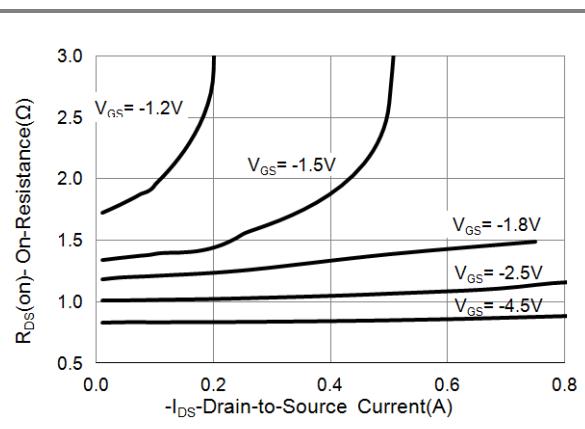


Fig.3 On-Resistance vs. Drain Current

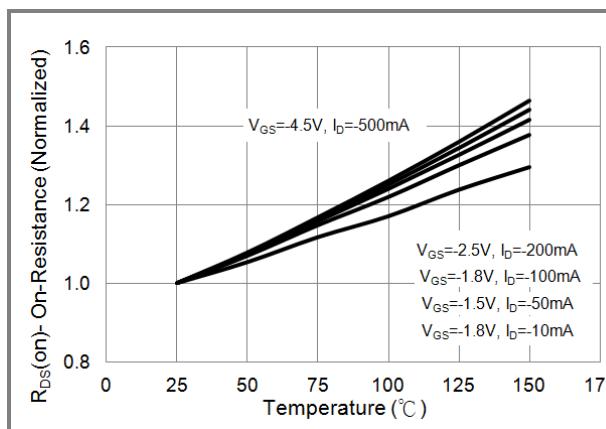


Fig.4 On-Resistance vs. Junction temperature

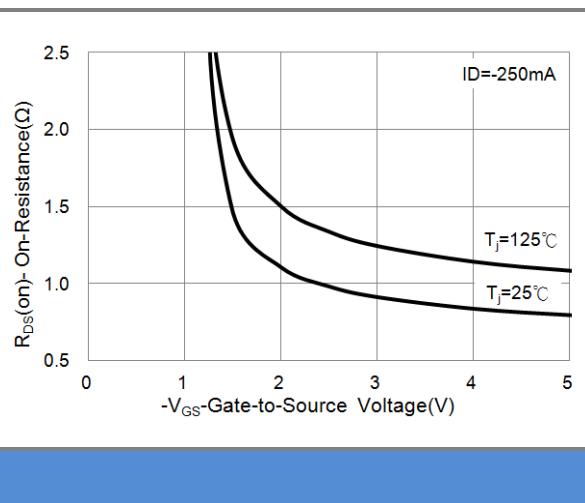


Fig.5 On-Resistance vs. Gate-to-Source Voltage

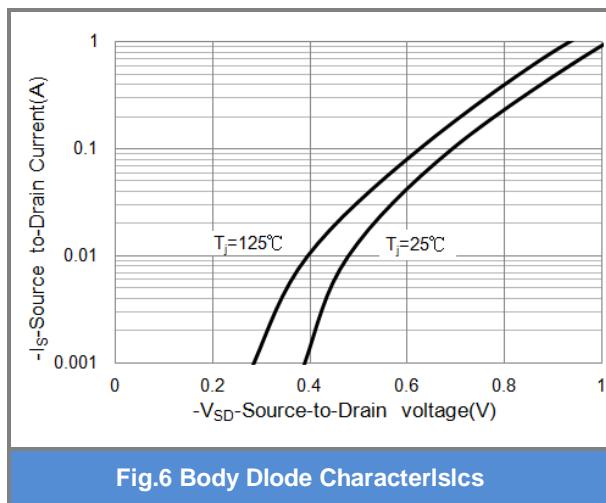


Fig.6 Body Diode Characteristics



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P-Channel TYPICAL CHARACTERISTIC CURVES

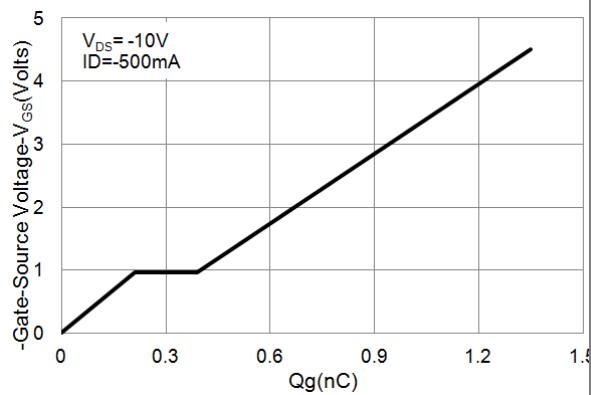


Fig.7 Gate-Charge Characteristics

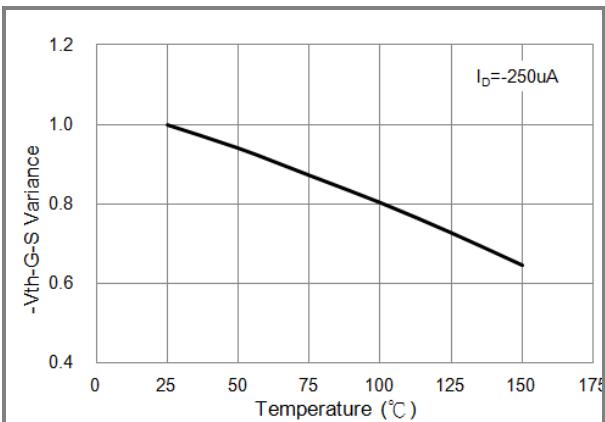


Fig.8 Threshold Voltage Variation with Temperature.

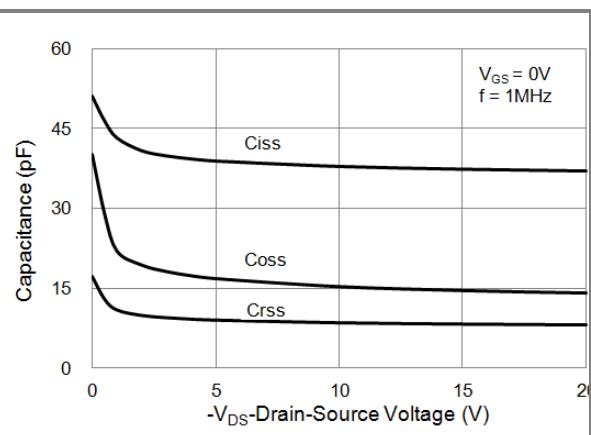


Fig.9 Threshold Voltage Variation with Temperature.

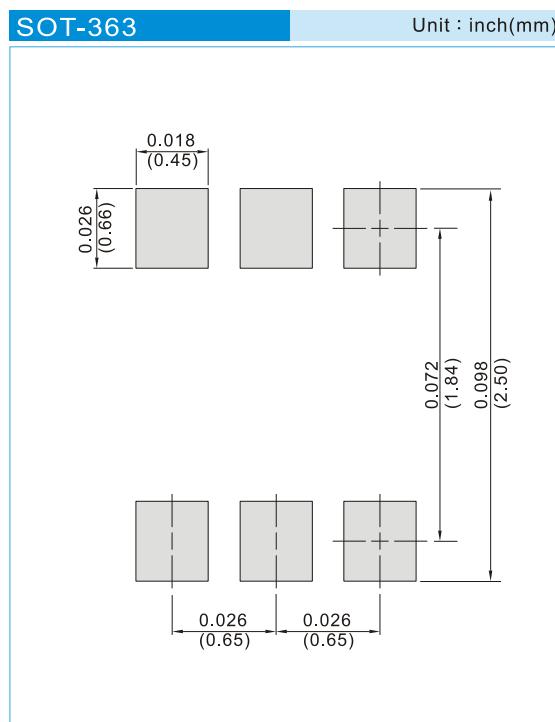


PJT7601

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJT7601_R1_00001	SOT-363	3K pcs / 7" reel	T61	Halogen free
PJT7601_R2_00001	SOT-363	10K pcs / 13" reel	T61	Halogen free

MOUNTING PAD LAYOUT





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